ELSEVIER

Thin Solid Films 280 (1996) 285

thin solid films

Author Index of Volume 280

Acharya, H.N., 20
Adamik, M., 5
Afonso, C.N., 278
Al-Shareef, H.N., 265
An, J.Y., 115
Anis, M.K., 262
Asim, H., 262

Ballif, C., 67
Barna, P.B., 5
Baxendale, M., 117
Bay, H.L., 107
Bollmeier, T., 147
Borgmann, D., 171
Brückner, W., 227
Brunel, M., 56
Bunshah, R.F., 256

Cameron, D.C., 221
Carpio, R.A., 37
Chan, P.W., 1
Chen, H.C., 188
Chen, X., 265
Choi, J.C., 115
Chopra, K.L., 20
Choy, C.L., 1
Clarke, G.A., 130
Czerwinski, F., 199

Dahman, H., 56
Dauscher, A., 61
De Veirman, A.E.M., 136
Dikaev, Yu.M., 163
Dimitrov, D., 278
Doerr, H.J., 256
Donchev, T., 112

Easwarakhanthan, T., 183
Edelmann, J., 227
Eldridge, J.E., 130

Fainer, N.I., 16
Farouk, B., 204

Galkin, N.G., 211
Ghosh, T.B., 20, 167
Guilloux-Viry, M., 76

Hacke, M., 107
Hodes, G., 86
Hynninen, P.H., 244

Ishikawa, A., 233
Islam, M.N., 20

Janča, J., 26
Jeong, B.S., 115
Jing, C., 90
Jou, S., 256

Kaiser, U., 5
Kang, J.-K., 43
Khalifa, M., 56
Khan, M.S., 262
Khrustalev, A.B., 211
Kikuchi, R., 117
Kim, D.S., 204
Kim, T.W., 115
Kingon, A.I., 265
Kishida, S., 142
Knuth, Th., 227
Konstantinov, K., 112
Kools, J.C.S., 136
Kosinova, M.L., 16
Kotelyanskii, I.M., 163
Koumoto, K., 160
Kovacheva, D., 112
Kravchenko, V.B., 163
Kuwabara, K., 160
Kuznetsov, F.A., 16

Laux, S., 5
Lee, J.H., 204
Lee, Y.H., 204
Lemmetyinen, H., 244
Lévy, F., 67
Lévy-Clément, C., 86
Lichtenwalner, D.J., 265
Liu, S.-G., 271
Liu, Y.-Q., 271
Luzanov, V.A., 163

Manno, D., 249
Mantl, S., 107
Matsui, T., 117
Matsumoto, M., 238
McAleese, J., 152
McKenzie, D.R., 95
Melekh, B.T., 163
Moore, J.F., 101
Moser, J.H., 67

Nakamura, K.-I., 238
Neerinck, D.G., 136
Nesheva, D., 51
Neumann-Spallart, M., 86
Niwa, T., 233

Ohki, Y., 117
Ohlídal, I., 26
Ohtsuka, T., 124
Okabayashi, H., 142
Ollacarizqueta, M.A., 278
Ong, C.W., 1
Ota, E., 117

Padiou, J., 76
Park, H.L., 115
Park, Y.-B., 43
Parsons, R.R., 130
Perrin, A., 76
Pfender, E., 188
Plakatouras, J.C., 152
Ponomarev, E.A., 86

Rauschenbach, B., 147
Regula, M., 67
Reiss, G., 227
Rella, R., 249
Remy, M., 183
Rezig, B., 56
Rhee, S.-W., 43
Richter, W., 5
Rijks, Th.G.S.M., 136
Rossel, C., 76
Rührnschopf, K., 171
Rumyantsev, Yu.M., 16

Sáfrán, G., 5
Salman, E.G., 16
Scherrer, H., 61
Schweitzer, D., 147
Sergent, M., 76
Shinzawa, T., 142
Sitter, H., 83
Skripka, S.V., 211
Slangen, M.H.J., 136
Sreemany, M., 167
Stambolova, I., 112
Stankiewicz, B., 178
Starbov, N., 278
Steele, B.C.H., 152
Stifter, D., 83
Stritzker, B., 147
Strongin, D.R., 101
Sugai, K., 142

Takahashi, M., 124
Tang, W., 221
Tauber, A.Y., 244
Thomy, A., 61
Tkachenko, N.V., 244
Troisi, L., 249
Tsang, Y.C., 1
Tsuchida, T., 124
Tsujii, Y., 238

Ushio, Y., 233

Valli, L., 249
Velitchko, T.V., 211
Vinzelberg, H., 227

Wallace, W.E., 37
Wang, T.M., 90
Wang, W.J., 90
Wedler, G., 171
Wu, W.L., 37

Xie, Y., 130

Yin, Y., 95
Yoshimoto, T., 238
Yoshimura, S., 117
Yudasaka, M., 117
Yukawa, T., 160

Zajíčková, L., 26
Zhao, X.-A., 1
Zhu, D.-B., 271

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ELSEVIER

Thin Solid Films 280 (1996) 287–290

thin solid films

Subject Index of Volume 280

Alkali halides
electronic properties of the Ge/RbF/GaAs system: the effect of the RbF intralayer, 178
Alloys
in-situ measurement of stress generated during electrocrystallization of Fe–Ni alloys, 199
degradation of NiCr/CuNiMn/NiCr films on alumina substrates, 227
Aluminium
titanium-containing hydrofluoric acid pretreatment for aluminum chemical vapor deposition, 142
Amorphous carbon
a theory for the formation of tetrahedral amorphous carbon including deposition rate effects, 95
Amorphous materials
mechanical properties of a-C:H and a-C:H/SiO_x nanocomposite thin films prepared by ion-assisted plasma-enhanced chemical vapor deposition, 204
amorphous semiconducting film containing nanometer particles of CuTCNQ: preparation, characterization and electrical switching property, 271
crystallization kinetics of Sb_xSe_{100-x} thin films, 278

Cadmium selenide
photoconductivity and recombination in amorphous Se/CdSe multilayers, 51
Cadmium sulphide
growth of PbS and CdS thin films by low-pressure chemical vapour deposition using dithiocarbamates, 16
Carbon nitride
effects of substrate temperature on the structure and properties of reactive pulsed laser deposited CN_x films, 1
Ceramics
the use of Ce(fod)$_4$ as a precursor for the growth of ceria films by metal–organic chemical vapour deposition, 152
Cerium
deposition of CeO_2 films including areas with the different orientation and sharp border between them, 163
Chalcogens
structural, chemical, and electrical characterisation of reactively sputtered WS_x thin films, 67
Chemical vapor deposition
graphite formation on Ni film by chemical vapor deposition, 117
Chemical vapour deposition
chemical–mechanical polishing of SiO_2 thin films studied by X-ray reflectivity, 37
effect of N_2O/SiH_4 ratio on the properties of low-temperature silicon oxide films from remote plasma chemical vapour deposition, 43
titanium-containing hydrofluoric acid pretreatment for aluminum chemical vapor deposition, 142
the use of Ce(fod)$_4$ as a precursor for the growth of ceria films by metal–organic chemical vapour deposition, 152
Chemical vapour deposition (CVD)
ultrathin silicon oxide films deposited by synchrotron irradiation of condensed layers of silanes and water, 101
Chromium
semiconducting and structural properties of $CrSi_2$ A-type epitaxial films on Si(111), 211
Coatings
implantation effect of diamond-like carbon films by 110 keV nitrogen ions, 90
microstructure of plasma-sprayed Ni–Al alloy coating on mild steel, 188
in-situ measurement of stress generated during electrocrystallization of Fe–Ni alloys, 199
Computer simulation
the infrared properties of magnetron-sputtered diamond-like thin films, 130
application of Rachinger's method to separate overlapped doublets in the X-ray photoelectron spectrum, 167
Conductivity
the effect of the isopoly tungstate anion on the composition and conductivity of polypyrrole composite films, 124
Contacts
low frequency dispersion in GaSe thin films, 262
Copper
electrodeposition of $CuInS_2$ from aqueous solution. Part I. Electrodeposition of Cu–S film, 160

Deposition process
growth structure investigation of MgF_2 and NdF_3 films grown by molecular beam deposition on CaF_2(111) substrates, 5
effect of N_2O/SiH_4 ratio on the properties of low-temperature silicon oxide films from remote plasma chemical vapour deposition, 43
electrochemical deposition of MoS_2 thin films by reduction of tetrathiomolybdate, 86
a theory for the formation of tetrahedral amorphous carbon including deposition rate effects, 95
electrodeposition of $CuInS_2$ from aqueous solution. Part I. Electrodeposition of Cu–S film, 160
deposition of CeO_2 films including areas with the different orientation and sharp border between them, 163
in-situ measurement of stress generated during electrocrystallization of Fe–Ni alloys, 199
Depth profiling
chemical–mechanical polishing of SiO_2 thin films studied by X-ray reflectivity, 37
Diamond
a theory for the formation of tetrahedral amorphous carbon including deposition rate effects, 95
the infrared properties of magnetron-sputtered diamond-like thin films, 130
electron emission characterization of diamond thin films grown from a solid carbon source, 256

Elsevier Science S.A.

Dielectric properties
low frequency dispersion in GaSe thin films, 262

Electrical conductivity
effects of substrate temperature on the structure and properties of reactive pulsed laser deposited CN_x films, 1
Electrical properties and measurements
degradation of NiCr/CuNiMn/NiCr films on alumina substrates, 227
electron emission characterization of diamond thin films grown from a solid carbon source, 256
Electrochemistry
electrochemical deposition of MoS_2 thin films by reduction of tetrathiomolybdate, 86
the effect of the isopoly tungstate anion on the composition and conductivity of polypyrrole composite films, 124
electrodeposition of $CuInS_2$ from aqueous solution. Part I. Electrodeposition of Cu–S film, 160
in-situ measurement of stress generated during electrocrystallization of Fe–Ni alloys, 199
electroluminescent zinc sulphide devices produced by sol–gel processing, 221
degradation of the electrochromic nickel oxide film upon redox cycling, 233
Electronic devices
amorphous semiconducting film containing nanometer particles of CuTCNQ: preparation, characterization and electrical switching property, 271
Electron microscopy
structural, chemical, and electrical characterisation of reactively sputtered WS_x thin films, 67
Ellipsometry
comparison between newly developed and classical determinations of index and thickness of thin films on substrates by ellipsometry, 183
Epitaxy
epitaxially grown molybdenum thin films deposited by laser ablation on (100)MgO substrates, 76
thickness correlated effects of the crystal and surface structure of C_{60} thin films grown on mica by hot wall epitaxy, 83
twinning of $YBa_2Cu_3O_7$ thin films on different substrates, 147
deposition of CeO_2 films including areas with the different orientation and sharp border between them, 163
semiconducting and structural properties of $CrSi_2$ A-type epitaxial films on Si(111), 211

Fourier transform infrared spectroscopy
implantation effect of diamond-like carbon films by 110 keV nitrogen ions, 90
Fullerenes
thickness correlated effects of the crystal and surface structure of C_{60} thin films grown on mica by hot wall epitaxy, 83

Gallium
site symmetry of Yb^{3+} in $In_{0.5}Ga_{0.5}P$, 115
Galliun selenide
low frequency dispersion in GaSe thin films, 262
Graphite
graphite formation on Ni film by chemical vapor deposition, 117
growth mechanism
ultrathin silicon oxide films deposited by synchrotron irradiation of condensed layers of silanes and water, 101
MBE growth and characterization of buried silicon oxide films on Si(100), 107
growth of Fe on Si (100) at room temperature and formation of iron silicide, 171

Hardness
mechanical properties of a-C:H and a-C:H/SiO_x nanocomposite thin films prepared by ion-assisted plasma-enhanced chemical vapor deposition, 204

Indium phosphide
site symmetry of Yb^{3+} in $In_{0.5}Ga_{0.5}P$, 115
Infrared spectroscopy
the infrared properties of magnetron-sputtered diamond-like thin films, 130
Insulators
electronic properties of the Ge/RbF/GaAs system: the effect of the RbF intralayer, 178
Interfaces
effect of N_2O/SiH_4 ratio on the properties of low-temperature silicon oxide films from remote plasma chemical vapour deposition, 43
electronic properties of the Ge/RbF/GaAs system: the effect of the RbF intralayer, 178
microstructure of plasma-sprayed Ni–Al alloy coating on mild steel, 188
Ion implantation
implantation effect of diamond-like carbon films by 110 keV nitrogen ions, 90
IR absorption
effects of substrate temperature on the structure and properties of reactive pulsed laser deposited CN_x films, 1
Iron
iron pyrite films prepared by sulfur vapor transport, 56
growth of Fe on Si (100) at room temperature and formation of iron silicide, 171

Langmuir–Blodgett films
a trough with radial compression for studies of monolayers and fabrication of Langmuir–Blodgett films, 238
photoinduced energy and electron transfer of covalently linked zinc(II)-pyropheophytin-anthraquinone molecules in monolayers of Langmuir–Blodgett films, 244
Langmuir–Blodgett films of Cu(II)-tetrakis(3,3-dimethylbutoxycarbonyl)phthalocyanine: a spectrophotometric and TEM analysis of their structure and morphology, 249
Laser ablation
pulsed laser deposition of Bi_2Te_3 thin films, 61
epitaxially grown molybdenum thin films deposited by laser ablation on (100)MgO substrates, 76
twinning of $YBa_2Cu_3O_7$ thin films on different substrates, 147
Luminescence
electroluminescent zinc sulphide devices produced by sol–gel processing, 221

Metallization
analysis of the oxidation kinetics and barrier layer properties of ZrN and Pt/Ru thin films for DRAM applications, 265
Mica
thickness correlated effects of the crystal and surface structure of C_{60} thin films grown on mica by hot wall epitaxy, 83
Molecular beam epitaxy
MBE growth and characterization of buried silicon oxide films on Si(100), 107
Molybdenum
epitaxially grown molybdenum thin films deposited by laser ablation on (100)MgO substrates, 76
Molybdenum disulphide
electrochemical deposition of MoS_2 thin films by reduction of tetrathiomolybdate, 86
Monolayers
a trough with radial compression for studies of monolayers and fabrication of Langmuir–Blodgett films, 238

photoinduced energy and electron transfer of covalently linked zinc(II)-pyropheophytin-anthraquinone molecules in monolayers of Langmuir–Blodgett films, 244
Multilayers
photoconductivity and recombination in amorphous Se/CdSe multilayers, 51

Nanostructures
growth structure investigation of MgF_2 and NdF_3 films grown by molecular beam deposition on $CaF_2(111)$ substrates, 5
mechanical properties of a-C:H and a-C:H/SiO_x nanocomposite thin films prepared by ion-assisted plasma-enhanced chemical vapor deposition, 204
electron emission characterization of diamond thin films grown from a solid carbon source, 256
Nickel
graphite formation on Ni film by chemical vapor deposition, 117
Nickel oxide
degradation of the electrochromic nickel oxide film upon redox cycling, 233

Optical properties
plasma-enhanced chemical vapour deposition of thin films from tetraethoxysilane and methanol: optical properties and XPS analyses, 26
iron pyrite films prepared by sulfur vapor transport, 56
degradation of the electrochromic nickel oxide film upon redox cycling, 233
Optical spectroscopy
Langmuir–Blodgett films of Cu(II)-tetrakis(3,3-dimethylbutoxycarbonyl)phthalocyanine: a spectrophotometric and TEM analysis of their structure and morphology, 249
Optical transmission
effects of substrate temperature on the structure and properties of reactive pulsed laser deposited CN_x films, 1
Organic substances
photoinduced energy and electron transfer of covalently linked zinc(II)-pyropheophytin-anthraquinone molecules in monolayers of Langmuir–Blodgett films, 244
amorphous semiconducting film containing nanometer particles of CuTCNQ: preparation, characterization and electrical switching property, 271
Oxidation
analysis of the oxidation kinetics and barrier layer properties of ZrN and Pt/Ru thin films for DRAM applications, 265
Oxides
new $LaCu_{0.5}Mn_{0.5}O_3$ thin films deposited by the sol–gel process on different substrates, 112
the use of $Ce(fod)_4$ as a precursor for the growth of ceria films by metal–organic chemical vapour deposition, 152

Phase transitions
crystallization kinetics of Sb_xSe_{100-x} thin films, 278
Photoconductivity
photoconductivity and recombination in amorphous Se/CdSe multilayers, 51
Photothermal deflection spectroscopy
effects of substrate temperature on the structure and properties of reactive pulsed laser deposited CN_x films, 1
Plasma processing and deposition
growth of PbS and CdS thin films by low-pressure chemical vapour deposition using dithiocarbamates, 16
plasma-enhanced chemical vapour deposition of thin films from tetraethoxysilane and methanol: optical properties and XPS analyses, 26
microstructure of plasma-sprayed Ni–Al alloy coating on mild steel, 188
mechanical properties of a-C:H and a-C:H/SiO_x nanocomposite thin films prepared by ion-assisted plasma-enhanced chemical vapor deposition, 204
electron emission characterization of diamond thin films grown from a solid carbon source, 256
Polymers
the effect of the isopoly tungstate anion on the composition and conductivity of polypyrrole composite films, 124

Raman scattering
implantation effect of diamond-like carbon films by 110 keV nitrogen ions, 90
Reaction kinetics
analysis of the oxidation kinetics and barrier layer properties of ZrN and Pt/Ru thin films for DRAM applications, 265
Reactive pulsed laser deposition
effects of substrate temperature on the structure and properties of reactive pulsed laser deposited CN_x films, 1

Scanning electron microscopy
new $LaCu_{0.5}Mn_{0.5}O_3$ thin films deposited by the sol–gel process on different substrates, 112
Selenides
photoconductivity and recombination in amorphous Se/CdSe multilayers, 51
crystallization kinetics of Sb_xSe_{100-x} thin films, 278
Semiconductors
iron pyrite films prepared by sulfur vapor transport, 56
electrochemical deposition of MoS_2 thin films by reduction of tetrathiomolybdate, 86
site symmetry of Yb^{3+} in $In_{0.5}Ga_{0.5}P$, 115
electronic properties of the Ge/RbF/GaAs system: the effect of the RbF intralayer, 178
semiconducting and structural properties of $CrSi_2$ A-type epitaxial films on Si(111), 211
Silicides
growth of Fe on Si (100) at room temperature and formation of iron silicide, 171
Silicon
semiconducting and structural properties of $CrSi_2$ A-type epitaxial films on Si(111), 211
Silicon oxide
chemical–mechanical polishing of SiO_2 thin films studied by X-ray reflectivity, 37
effect of N_2O/SiH_4 ratio on the properties of low-temperature silicon oxide films from remote plasma chemical vapour deposition, 43
ultrathin silicon oxide films deposited by synchrotron irradiation of condensed layers of silanes and water, 101
MBE growth and characterization of buried silicon oxide films on Si(100), 107
Solid electrolyte interface
the use of $Ce(fod)_4$ as a precursor for the growth of ceria films by metal–organic chemical vapour deposition, 152
Sputtering
structural, chemical, and electrical characterisation of reactively sputtered WS_x thin films, 67
the infrared properties of magnetron-sputtered diamond-like thin films, 130
grain size and strain in thin sputter-deposited $Ni_{0.8}Fe_{0.2}$ and Cu films, 136
degradation of the electrochromic nickel oxide film upon redox cycling, 233
analysis of the oxidation kinetics and barrier layer properties of ZrN and Pt/Ru thin films for DRAM applications, 265
Stress
in-situ measurement of stress generated during electrocrystallization of Fe–Ni alloys, 199

degradation of NiCr/CuNiMn/NiCr films on alumina substrates, 227
Structural properties
grain size and strain in thin sputter-deposited $Ni_{0.8}Fe_{0.2}$ and Cu films, 136
twinning of $YBa_2Cu_3O_7$ thin films on different substrates, 147
semiconducting and structural properties of $CrSi_2$ A-type epitaxial films on Si(111), 211
degradation of NiCr/CuNiMn/NiCr films on alumina substrates, 227
Langmuir–Blodgett films of Cu(II)-tetrakis(3,3-dimethylbutoxy-carbonyl)phthalocyanine: a spectrophotometric and TEM analysis of their structure and morphology, 249
crystallization kinetics of Sb_xSe_{100-x} thin films, 278
Sulphides
growth of PbS and CdS thin films by low-pressure chemical vapour deposition using dithiocarbamates, 16
electrodeposition of $CuInS_2$ from aqueous solution. Part I. Electro-deposition of Cu–S film, 160
electroluminescent zinc sulphide devices produced by sol–gel processing, 221
Sulphur
iron pyrite films prepared by sulfur vapor transport, 56
a trough with radial compression for studies of monolayers and fabrication of Langmuir–Blodgett films, 238
Surface composition
pulsed laser deposition of Bi_2Te_3 thin films, 61
application of Rachinger's method to separate overlapped doublets in the X-ray photoelectron spectrum, 167
Surface defects
deposition of CeO_2 films including areas with the different orientation and sharp border between them, 163
Surface morphology
new $LaCu_{0.5}Mn_{0.5}O_3$ thin films deposited by the sol–gel process on different substrates, 112
titanium-containing hydrofluoric acid pretreatment for aluminum chemical vapor deposition, 142
Surface pressure
a trough with radial compression for studies of monolayers and fabrication of Langmuir–Blodgett films, 238
Surface roughness
chemical–mechanical polishing of SiO_2 thin films studied by X-ray reflectivity, 37
Surface structure
thickness correlated effects of the crystal and surface structure of C_{60} thin films grown on mica by hot wall epitaxy, 83

Tellurium
pulsed laser deposition of Bi_2Te_3 thin films, 61
Titanium
titanium-containing hydrofluoric acid pretreatment for aluminum chemical vapor deposition, 142
Transmission electron microscopy
grain size and strain in thin sputter-deposited $Ni_{0.8}Fe_{0.2}$ and Cu films, 136
microstructure of plasma-sprayed Ni–Al alloy coating on mild steel, 188
Langmuir–Blodgett films of Cu(II)-tetrakis(3,3-dimethylbutoxy-carbonyl)phthalocyanine: a spectrophotometric and TEM analysis of their structure and morphology, 249
Transmission electron microscopy (TEM)
growth structure investigation of MgF_2 and NdF_3 films grown by molecular beam deposition on CaF_2(111) substrates, 5
Tungsten
structural, chemical, and electrical characterisation of reactively sputtered WS_x thin films, 67
Tungsten oxide
the effect of the isopoly tungstate anion on the composition and conductivity of polypyrrole composite films, 124

X-ray diffraction
effects of substrate temperature on the structure and properties of reactive pulsed laser deposited CN_x films, 1
growth of PbS and CdS thin films by low-pressure chemical vapour deposition using dithiocarbamates, 16
XPS and X-ray diffraction studies of aluminum-doped zinc oxide transparent conducting films, 20
pulsed laser deposition of Bi_2Te_3 thin films, 61
new $LaCu_{0.5}Mn_{0.5}O_3$ thin films deposited by the sol–gel process on different substrates, 112
grain size and strain in thin sputter-deposited $Ni_{0.8}Fe_{0.2}$ and Cu films, 136
twinning of $YBa_2Cu_3O_7$ thin films on different substrates, 147
X-ray emission
application of Rachinger's method to separate overlapped doublets in the X-ray photoelectron spectrum, 167
X-ray photoelectron spectroscopy
effects of substrate temperature on the structure and properties of reactive pulsed laser deposited CN_x films, 1
XPS and X-ray diffraction studies of aluminum-doped zinc oxide transparent conducting films, 20
plasma-enhanced chemical vapour deposition of thin films from tetra-ethoxysilane and methanol: optical properties and XPS analyses, 26
application of Rachinger's method to separate overlapped doublets in the X-ray photoelectron spectrum, 167
X-ray photoelectron spectroscopy (XPS)
ultrathin silicon oxide films deposited by synchrotron irradiation of condensed layers of silanes and water, 101
growth of Fe on Si (100) at room temperature and formation of iron silicide, 171

Ytterbium
site symmetry of Yb^{3+} in $In_{0.5}Ga_{0.5}P$, 115

Zinc
electroluminescent zinc sulphide devices produced by sol–gel processing, 221
photoinduced energy and electron transfer of covalently linked zinc(II)-pyropheophytin-anthraquinone molecules in mono-layers of Langmuir–Blodgett films, 244
Zinc oxide
XPS and X-ray diffraction studies of aluminum-doped zinc oxide transparent conducting films, 20